



**ELEN E3106: Solid State Devices and Materials**  
**Electrical Engineering**  
**Fall 2025**

**COURSE DESCRIPTION**

Semiconductor devices are the underlying technology in every solid state active electronic circuit. This course will introduce the fundamental concepts of semiconductor physics and use them to construct fundamental device models for PN diodes, BJTs, and MOSFETs. We will begin with crystal structure and energy band theory of solids. Carrier concentration and drift/diffusion transport will be examined. Along the way, we will see how the same device fundamentals can be used to explain a number of other charge carrier drift/diffusion-based devices including junctions, photodetectors, solar cells, and light emitting devices. Fabrication techniques and device process variation will be covered. This course will build a student's knowledge of semiconductor fundamentals.

**COURSE SCHEDULE**

**Time:** Tuesday, Thursday 11:40am - 12:55pm

**Location:** International Affairs Building (IAB) 417

**INSTRUCTOR**

Prof. Savannah Eisner  
Mudd Building, Office 1328  
[savannah.eisner@columbia.edu](mailto:savannah.eisner@columbia.edu)

**TEACHING ASSISTANT (TA)**

Ethan Liu  
[yl5188@columbia.edu](mailto:yl5188@columbia.edu)

**COURSE ASSISTANTS (CAs)**

Akanksha Sahoo  
[as7466@columbia.edu](mailto:as7466@columbia.edu)

Sunny Hu  
[yh3553@columbia.edu](mailto:yh3553@columbia.edu)

**OFFICE HOURS (Tentative – check back after first week of class)**

Prof. Eisner: TBD

Ethan (TA): TBD

**RECITATION (Tentative – check back after first week of class)**

Ethan (TA): 11:45am on Fridays (location TBD)

**CREDITS**

3.5 credits

**TEXTBOOKS**

**Required:** B. G. Streetman, S. K. Banerjee, *Solid State Electronic Devices*, 7<sup>th</sup> ed., Pearson/Prentice Hall, 2014. ISBN-10: 0133356035. ISBN-13: 978-0133356038.

**Required (free online):** C. C. Hu, *Modern Semiconductor Devices for Integrated Circuits*, 3<sup>rd</sup> ed., Wiley, 2007. (<https://www.chu.berkeley.edu/modern-semiconductor-devices-for-integrated-circuits-chenming-calvin-hu-2010/>)

**GRADING POLICY**

- 30% Homework
- 20% Exam 1
- 20% Exam 2
- 30% Final Exam

**Homework**

A total of 9 problem sets will be assigned as homework. Homework will be due Fridays by 5pm ET via submission on Courseworks.

**Exams**

Two exams will be administered during regularly scheduled class time. The exams will be closed book and notes will not be allowed. A formula and constants sheet will be provided. Calculator required. You will receive an automatic zero if the TA or instructor sees your phone during the exam.

**Final Exam**

The final exam will be administered at the time and location specified by the registrar (tentative time: Thursday December 18<sup>th</sup> 4:10-7pm). The final will be closed book and notes will not be allowed. A formula and constants sheet will be provided. Calculator required.

Please refer to the [School Handbook](#) for further details on grading and good academic standing.

**COURSE COMMUNICATION****Courseworks**

This will be the main hub for this class. It will serve as a repository for all course files including homework assignments and solutions, grades, lecture slides, annotated lecture slides, and lecture recordings. Homework assignments will also be submitted here.

### **Ed Discussion**

We will be using Ed Discussion, which is integrated into Courseworks, as an online discussion and communication tool. Rather than emailing questions on the homework or technical concepts to the teaching staff, we encourage you to post your questions on Ed Discussion. Questions reach and benefit all students in the class. The staff will do our best to answer questions promptly.

## **POLICIES AND EXPECTATIONS**

### **Homework Policy**

Your homework set with the lowest grade, including no submission, will be dropped (e.g. it will not count towards your grade). Late homework will be accepted within 48 hours with the following penalty: -20% for 0-24 hours late, and -40% for 24-48 hours late. Example: Homework is due Friday at 5pm. Homework sets submitted by 5pm Saturday will receive a maximum grade of 80%, while homework sets submitted by 5pm Sunday will receive a maximum grade of 60%. Under no circumstances will other extensions be granted unless the instructor receives official notice from the Center for Student Advising that you will require academic accommodations. Technical issues are not an accepted excuse for late work. In the event you experience a technical issue that prevents you from uploading to Courseworks, it is expected that you will email the homework to the TA and the instructor by the deadline INCLUDING a screenshot of the ticket you submit to CUTT for help with the technical issue precluding submission on Courseworks.

### **Academic Integrity**

Students are required to adhere to Columbia University guidelines on academic integrity. For more information on student policies, please visit the Academic Integrity website (<https://www.cc-seas.columbia.edu/integrity>) and the Center for Student Success and Intervention website (<https://cssi.columbia.edu/content/learn-about-policies>). A list of general Columbia Engineering Academic Policies can be found on the website (<https://www.engineering.columbia.edu/academics/policies>).

### **Collaboration**

Students are allowed to work together on the homework sets. Each student must submit the assignment in their own personalized document or handwriting, with the solution for each problem fully worked out, to receive credit. If you have any questions regarding this policy, please ask the instructor or TA.

### **Exam Conflicts and Accommodations**

If you require an accommodation for a documented disability (see policy below) or a change in schedule due to a religious observance, contact the instructor at least a week in advance. Other than these two scenarios, make-up exams will not be given unless the instructor receives official notice

from the Center for Student Advising that you will require academic accommodations. If an exam is missed without prior approval from the instructor it will receive zero credit.

### **Disability Access**

In order to receive disability-related academic accommodations, students must first be registered with the Office of Disability Services (ODS). Students who have or think they may have a disability are invited to contact ODS for a confidential discussion at 212.854.2388 (V) 212.854.2378 (TTY), or by email at [disability@columbia.edu](mailto:disability@columbia.edu). If you have already registered with ODS, please speak to your instructor to ensure that they have been notified of your recommended accommodations at least one week before any exam.

## **COURSE LEARNING OBJECTIVES**

By the time you complete this course, you will master:

- Charge transport and carrier statistic equations relevant to crystalline semiconductors
- Energy band diagrams and their applications
- Characteristics of PN junctions and PN diode devices
- BJT characteristics, including internal, small signal macroscopic, and large signal macroscopic models
- MOS capacitor characteristics
- MOSFET characteristics, including internal, small signal macroscopic, and large signal macroscopic models
- Applications of these principles to basic optical energy conversion devices, including solar cells and LEDs

## **ADDITIONAL RESOURCES**

### **Free Online Resources**

- B. Van Zeghbroeck, *Principles of Semiconductor Devices*, a free online textbook. (<https://www.eletrica.ufpr.br/graduacao/e-books/Principles%20Of%20Semiconductor%20Devices.pdf>)
- ECE 440 on nanoHUB (<https://nanohub.org/resources/5221>)
- Britney Spears' guide to semiconductor physics (<http://britneyspears.ac/lasers.htm>)

### **More Resources**

- D. K. Bhattacharya, R. Sharma, *Solid State Electronic Devices*, 2<sup>nd</sup> edition, Oxford Univeristy Press, 2013. (available for free through Columbia libraries/Knovel. Click next to green checkmark here: <https://clio.columbia.edu/catalog/12110723?counter=1>)
- R. F. Pierret, *Semiconductor Device Fundamentals*, Addison-Wesley, 1996.
- S. M. Sze and K.K. Ng, *Physics of Semiconductor Devices*, 3rd ed., Wiley, 2007.

## COURSE SCHEDULE

Please note: course schedule is subject to change as the semester progresses based on our pace.

Week	Date	Lecture	Topic	Reading and assignments
1 <sup>st</sup>	Sept 2 <sup>nd</sup> (Tues)	1	Introduction to the course and semiconductor devices	Read syllabus
	Sept 4 <sup>th</sup> (Thurs)	2	Semiconductors & Crystal Properties	Streeman & Bannerjee §1.1, 1.2. Review Ch. 2
2 <sup>nd</sup>	Sept 9 <sup>th</sup> (Tues)	3	Bonding Forces & Energy Bands in Solids	Streeman & Bannerjee §3.1
	Sept 11 <sup>th</sup> (Thurs)	4	Charge Carriers in Semiconductors & Intro to Fermi Levels	Streeman & Bannerjee §3.2, 3.3.1 <b>HW 1 due Fri Sept 12<sup>th</sup> by 5pm</b>
3 <sup>rd</sup>	Sept 16 <sup>th</sup> (Tues)	5	Carriers: Temperature dependency, <b>drift</b> , mobility, and resistance	Streeman & Bannerjee §3.3.2-3.3.4, 3.4
	Sept 18 <sup>th</sup> (Thurs)	6	Diffusion of Carriers	Streeman & Bannerjee §4.4.1-4.4.4 <b>HW 2 due Fri Sept 19<sup>th</sup> by 5pm</b>
4 <sup>th</sup>	Sept 23 <sup>rd</sup> (Tues)	7	Optical absorption, luminescence, carrier lifetime and photoconductivity (end of coverage for Exam 1)	Streeman & Bannerjee §4.1-4.3
	Sept 25 <sup>th</sup> (Thurs)	8	p-n Junctions Part I	Streeman & Bannerjee §5.2 <b>HW 3 due Fri Sept 26<sup>th</sup> by 5pm</b>
5 <sup>th</sup>	Sept 30 <sup>th</sup> (Tues)	<b>Exam 1 (Chapters 1, 3, and 4)</b>		
	Oct 2 <sup>nd</sup> (Thurs)	9	p-n Junctions Part II	Streeman & Bannerjee §5.2
6 <sup>th</sup>	Oct 7 <sup>th</sup> (Tues)	10	Metal-Semiconductor Junctions and Contacts	Streeman & Bannerjee §5.7; C. Hu Ch. 4 Part III
	Oct 9 <sup>th</sup> (Thurs)	11	Device Fabrication	Streeman & Bannerjee §5.1 <b>HW 4 due Fri Oct 10<sup>th</sup> by 5pm</b>
7 <sup>th</sup>	Oct 14 <sup>th</sup> (Tues)	12	Optoelectronics Part I: Solar Cells & Photodiodes	Streeman & Bannerjee §8.1
	Oct 16 <sup>th</sup> (Thurs)	13	Optoelectronics Part II: LEDs and Lasers	Streeman & Bannerjee §8.2-8.4

				<b>HW 5 due Fri Oct 17<sup>th</sup> by 5pm</b>
8 <sup>th</sup>	Oct 21 <sup>st</sup> (Tues)	14	p-n Junction Breakdown and Narrow Base Diodes (end of coverage for Exam 2)	Streeman & Bannerjee §5.4
	Oct 23 <sup>rd</sup> (Thurs)	15	BJTs Part I	Streeman & Bannerjee §7.1-7.2 <b>HW 6 due Fri Oct 24<sup>th</sup> by 5pm</b>
9 <sup>th</sup>	Oct 28 <sup>th</sup> (Tues)	<b>Exam 2 (Chapters 5 and 8)</b>		
	Oct 30 <sup>th</sup> (Thurs)	16	BJTs Part II	C. Hu §8.1-8.4
10 <sup>th</sup>	Nov 4 <sup>th</sup> (Tues)	University Holiday; no class (Election Day)		
	Nov 6 <sup>th</sup> (Thurs)	17	BJTs Part III: Modes of Operation and Secondary Effects	C. Hu §8.4, 8.6-8.7
11 <sup>th</sup>	Nov 11 <sup>th</sup> (Tues)	18	BJTs Part IV: Models and Secondary Effects	C. Hu §8.6-8.10
	Nov 13 <sup>th</sup> (Thurs)	19	MOS Capacitor Part I	C. Hu §5.1-5.5 <b>HW 7 due Fri Nov 14<sup>th</sup> by 5pm</b>
12 <sup>th</sup>	Nov 18 <sup>th</sup> (Tues)	20	MOS Capacitor Part II	C. Hu §5.6, 5.10.1
	Nov 20 <sup>th</sup> (Thurs)	21	MOSFETs Part I	<b>HW 8 due Fri Nov 21<sup>st</sup> by 5pm</b>
13 <sup>th</sup>	Nov 25 <sup>th</sup> (Tues)	22	MOSFETs Part II	
	Nov 27 <sup>th</sup> (Thurs)	University Holiday; no class (Thanksgiving)		
14 <sup>th</sup>	Dec 2 <sup>nd</sup> (Tues)	23	MOSFETs Part III	
	Dec 4 <sup>th</sup> (Thurs)	24	Review Session (Extra Credit Opportunity)	<b>HW 9 due Fri Dec 5<sup>th</sup> by 5pm</b>
	Dec 18 <sup>th</sup> (Thurs)	<b>Final Exam, 4:10 – 7pm (Location TBD)</b>		